NSN 5961-01-215-8819

Unitized Semiconductor Device Rectifier - Page 1 of 1



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Special Features:

Silicon; 5.000 in. Lg; 0.750 in. Maximum h; 0.750 in. Maximum w; two 0.375 in. Maximum h turret type terminals; two 6-32 thd, 0.250 in. D
mtg holes located 4.500 in. C to c along lg; 15000 volts peak inverse voltage; 21 volts forward voltage, dc; 1.00 amps

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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